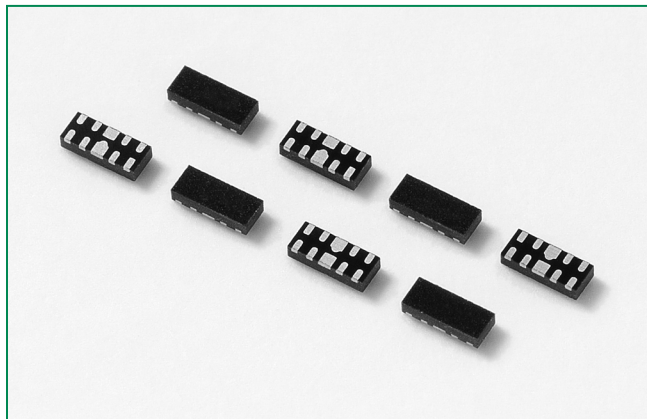
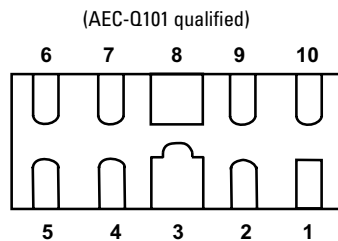


SP0524P Series 0.5pF Diode Array

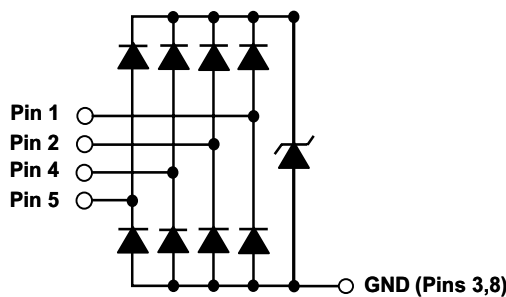


Pinout



*Pins 6, 7, 9, 10 are not internally connected but should be connected to the trace.

Functional Block Diagram



Additional Information



Life Support Note:
Not Intended for Use in Life Support or Life Saving Applications
 The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

Description

The SP0524P integrates 4 channels of ultra low capacitance rail-to-rail diodes and an additional zener diode to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). This robust device can safely absorb repetitive ESD strikes above the maximum level specified in the IEC 61000-4-2 international standard ($\pm 8\text{kV}$ contact discharge) without performance degradation. The extremely low loading capacitance also makes it ideal for protecting high speed signal pins such as HDMI, USB3.0, USB2.0, and IEEE 1394.

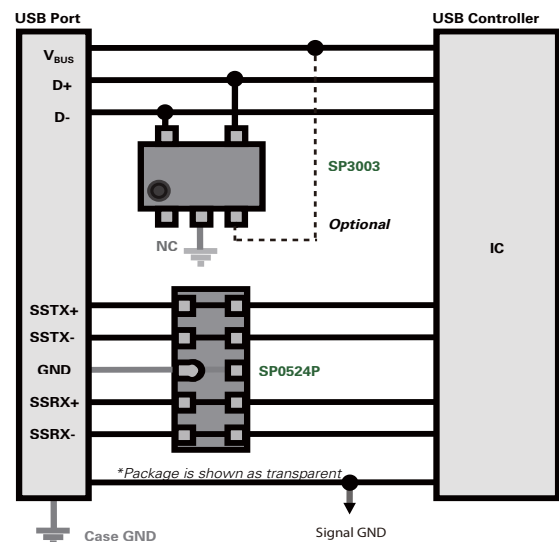
Features

- RoHS compliant and lead-free
- ESD, IEC 61000-4-2, $\pm 12\text{kV}$ contact, $\pm 25\text{kV}$ air
- EFT, IEC 61000-4-4, 40A ($t_p=5/50\text{ns}$)
- Lightning, IEC 61000-4-5, 2nd edition, 4A ($t_p=8/20\mu\text{s}$)
- Low capacitance of 0.5pF (TYP) per I/O
- Low leakage current of $1.5\mu\text{A}$ (MAX) at 5V
- Small form factor μDFN (JEDEC MO-229) package saves board space

Applications

- LCD/PDP TVs
- External Storages
- DVD/ Blue-Ray Players
- Desktops
- MP3/PMP
- Set Top Boxes
- Mobile Phones
- Notebooks
- Digital Cameras

Application Example for USB3.0



Absolute Maximum Ratings

Symbol	Parameter	Value	Units
I_{PP}	Peak Current ($t_p=8/20\mu s$)	4.0	A
T_{OP}	Operating Temperature	-40 to 125	°C
T_{STOR}	Storage Temperature	-55 to 150	°C

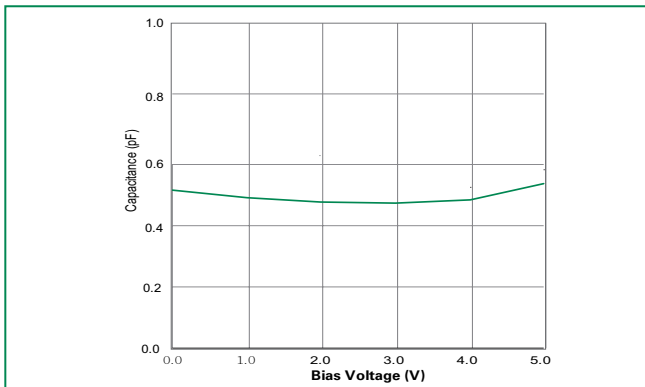
CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Electrical Characteristics ($T_{OP}=25^\circ C$)

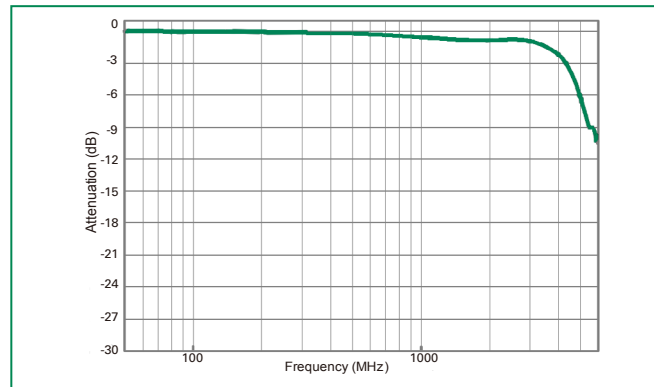
Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R \leq 1\mu A$			5.0	V
Reverse Breakdown Voltage	V_{BR}	$I_R = 1mA$	6	6.5		V
Reverse Leakage Current	I_{LEAK}	$V_R=5V$, Any I/O to GND			1.5	μA
Clamp Voltage ¹	V_C	$I_{PP}=1A$, $t_p=8/20\mu s$, Fwd		6.6		V
		$I_{PP}=2A$, $t_p=8/20\mu s$, Fwd		7.0		V
Dynamic Resistance	R_{DYN}	$(V_{C2} - V_{C1}) / (I_{PP2} - I_{PP1})$		0.4		Ω
ESD Withstand Voltage ¹	V_{ESD}	IEC 61000-4-2 (Contact)	± 12			kV
		IEC 61000-4-2 (Air)	± 25			kV
Diode Capacitance ¹	$C_{I/O-GND}$	Reverse Bias=0V, f=1 MHz		0.5	0.55	pF
Diode Capacitance ¹	$C_{I/O-I/O}$	Reverse Bias=0V, f=1 MHz		0.3		pF

Note: ¹ Parameter is guaranteed by design and/or device characterization.

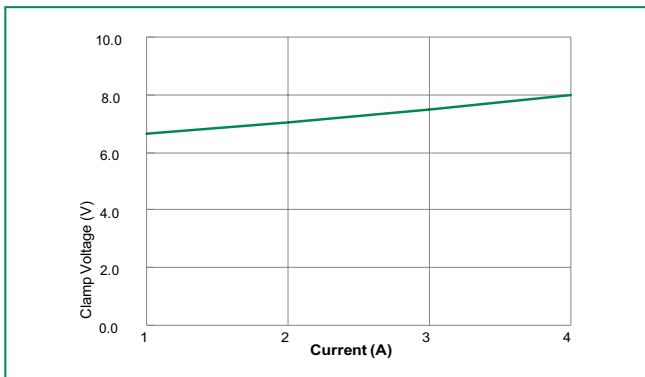
Capacitance vs. Bias Voltage



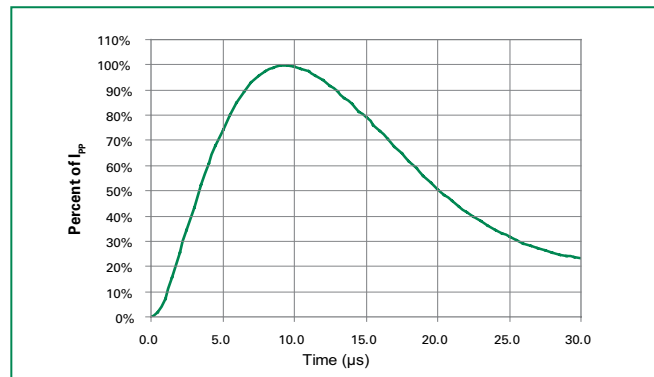
Insertion Loss (S21) I/O to GND



Clamping Voltage vs. I_{PP}

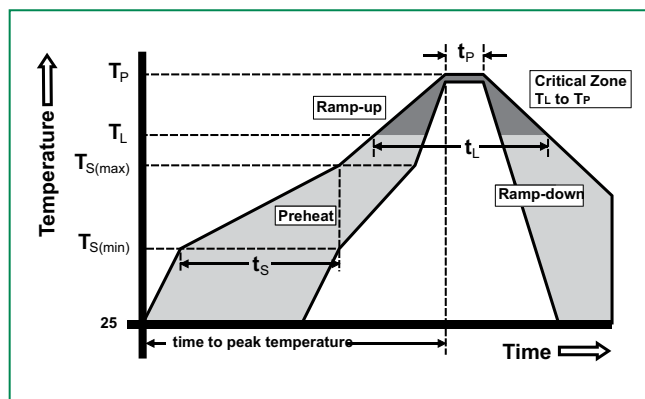


Pulse Waveform

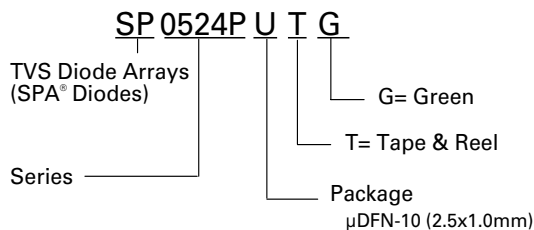


Soldering Parameters

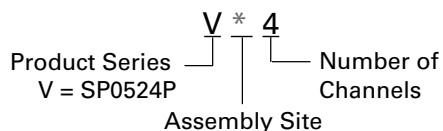
Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus) Temp (T_L) to peak		3°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Temperature (t_l)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		260°C



Part Numbering System



Part Marking System



Product Characteristics

Lead Plating	Pre-Plated Frame
Lead Material	Copper Alloy
Lead Coplanarity	0.0004 inches (0.102mm)
Substitute Material	Silicon
Body Material	Molded Epoxy
Flammability	UL 94 V-0

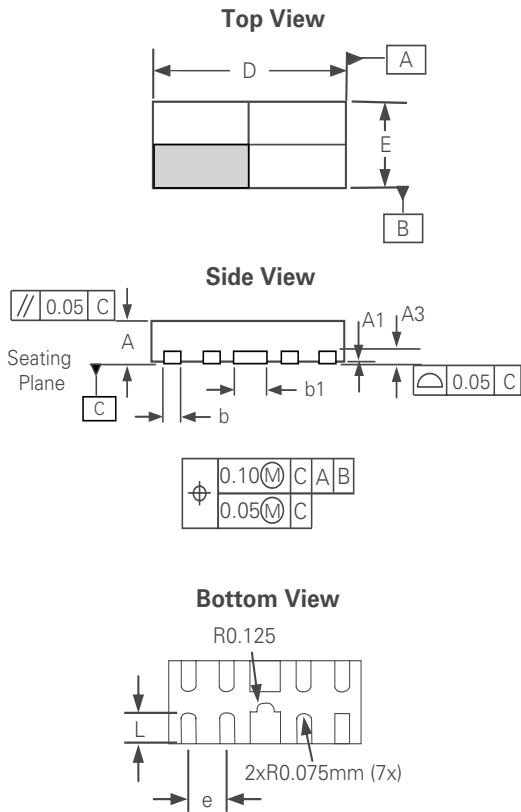
Notes :

1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

Ordering Information

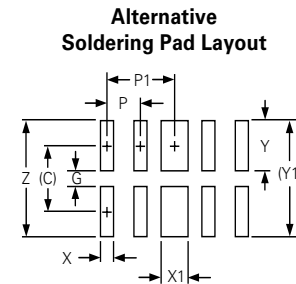
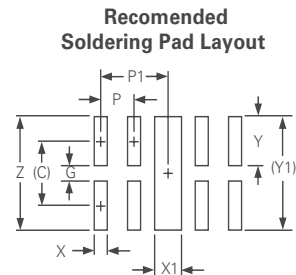
Part Number	Package	Marking	Min. Order Qty.
SP0524PUTG	μ DFN-10	V*4	3000

Package Dimensions — μ DFN-10 (2.5x1.0x0.5mm)

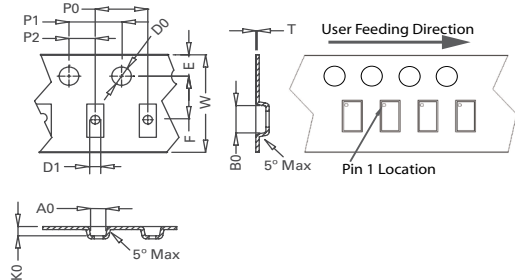


Package	μ DFN-10 (2.5x1.0x0.5mm)					
JEDEC	MO-229					
Symbol	Millimeters			Inches		
	Min	Nom	Max	Min	Nom	Max
A	0.48	0.515	0.55	0.019	0.020	0.021
A1	0.00	--	0.05	0.000		0.022
A3	0.125 Ref			0.005 Ref		
b	0.15	0.20	0.25	0.006	0.008	0.012
b1	0.35	0.40	0.45	0.014	0.016	0.018
D	2.40	2.50	2.60	0.094	0.098	0.102
E	0.90	1.00	1.10	0.035	0.039	0.043
e	0.50 BSC			0.020 BSC		
L	0.30	0.365	0.43	0.012	0.014	0.016

Soldering Pad Layout Dimensions		
	Inch	Millimeter
C	(0.034)	(0.875)
G	0.008	0.20
P	0.020	0.50
P1	0.039	1.00
X	0.008	0.20
X1	0.016	0.40
Y	0.027	0.675
Y1	(0.061)	(1.55)
Z	0.061	1.55



Embossed Carrier Tape & Reel Specification — μ DFN-10



Package	μ DFN-10 (2.5x1.0x0.5mm)
Symbol	Millimeters
A0	1.30 ± 0.10
B0	2.83 ± 0.10
D0	∅ 1.50 ± 0.10
D1	∅ 1.00 ± 0.25
E	1.75 ± 0.10
F	3.50 ± 0.05
K0	0.65 ± 0.10
P0	4.00 ± 0.10
P1	4.00 ± 0.10
P2	2.00 ± 0.05
T	0.254 ± 0.02
W	8.00 + 0.30 / - 0.10

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